

MAINTENANCE MANUAL LOGIC BOARD 19D901690G4 FOR MVS

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DESCRIPTION

The Logic Board (A1) controls the main operation of the MVS radio.

It is located in the bottom of the frame assembly underneath the Audio Board. Refer to the combination manual for a complete mechanical layout of the board. Figure 1 provides a Block Diagram of the Logic Board. Refer to the Table of Contents in this publication for IC data sheets with pinout information on integrated circuits and modules.

The Logic Board contains a microprocessor and associated memory circuits which include an EPROM for controlling the processor and a programmable "personality" EEPROM to store customer frequencies, tones and options. Programmable data is entered using an IBM compatible personal computer and a RS-232 interface. Refer to the programming manual for programming instructions.

CIRCUIT ANALYSIS

MICROPROCESSOR

Microprocessor U701 is an 8-bit processor that performs the logic functions to provide the control signals required in the radio. An external 11.0592 MHz crystal (Y701)

is used for the clock. The microprocessor controls the following:

- Synthesizer
- Transmit circuit
- Decoding of Channel Guard (tone or digital) and Type 99 tones
- Generation of Channel Guard (tone or digital)
- · Transmitter and receiver audio mute gates.

Serial data at a 300 baud rate is used for communication between the microprocessor and the Front Cap Assembly. U701 uses the KEYPAD SERIAL line to receive Control Panel commands from the microprocessor in the Front Cap Assembly. U701 sends data back on the DISPLAY SERIAL line to update the LCD. Both serial lines normally rest at 5 volts with the data causing the lines to go low.

 $\overline{\text{AUDIO MUTE}}$ protect the microprocessor from static discharges. These lines are pulled high to +5 volts through 50K ohm resistors inside the microprocessor.

ERASABLE PROM (EPROM)

EPROM U703 is a CMOS 8K byte device with an internal address latch. All information required by the microprocessor for system operation resides in this EPROM.

ELECTRICALLY ERASABLE PROM (EEPROM)

EEPROM U704 is a 512 x 8-bit memory device, designated the "personality" PROM. This personality PROM stores all required customer information which includes: Frequencies, Tones, and Options. The EEPROM also retains the status of all radio functions (channel selection, volume setting, scan channel list, and scan on-off function) to return the radio to the same mode of operation after power is turned off or removed from the radio.

The EEPROM can be conveniently programmed without any need for opening up the radio. This is accomplished through the microphone jack (J725). The serial data is routed through the Control Board to the EEPROM on the Logic Board.

For an optional 128 channel radio, U704 is replaced with a larger memory (2048 x 8-bit) EEPROM device (19A705553P1).

LATCH

Latch U702 is a CMOS, 3-state, non-inverting, D type flip-flop with the following functions.

- To activate the band switch on the RF Board (if used)
- To function as a digital-to-analog converter (DAC) by generating sine wave signalling tones using resistor network R704.
- To activate the FAST SQUELCH on the Audio Board.
- To activate the low pass filter bypass on the Audio Board when Type 99 tone signalling is used.

RELAY

The relay circuit consists of NPN buffer transistor Q701 and NPN relay driver transistor Q702. The relay is activated by the microprocessor when a Type 99 call is received, or when the public address option is enabled and the mic PTT is keyed. The circuit is capable of handling up to 150 milliamperes from an externally connected relay coil.

VOLTAGE REGULATOR

Voltage regulator U705 supplies a regulated +5 VDC to the microprocessor, the EPROM, the EEPROM and the latch circuit. A reset circuit is built into U705 to provide the microprocessor with a reset signal required during its power-up routine. A +8 volts regulated DC is supplied to regulator U705 from the 8 volt regulator U102, located on the RF Board.

BATTERY VOLTAGE FILTER

Transistor Q703 is a filter circuit for the switched A+battery voltage. This circuit is used to reduce "alternator whine" interference. SW A+ filtered (13 volts) is used on the Audio Board.



The CMOS Integrated Circuit devices used in this equipment can be destroyed by static discharges. Before handling one of these devices, the serviceman should discharge himself by touching the case of a bench test instrument that has a 3-prong power cord connected to an outlet with a known good earth ground. When soldering or desoldering a CMOS device, the soldering iron should also have a 3-prong power cord connected to an outlet with a known good earth ground. A battery operated soldering iron may be used in place of the regular soldering iron.

SERVICE NOTES

If a faulty Logic Board is suspected it may be useful to confirm this by substitution of a known good board.

DC CHECKS

Power for the Logic Board is supplied by the 8 volts on J702, Pin 3. This comes from the transmitter regulator U102.

- 1. Check for +5 volts ± 0.25 volts on U705, Pin 5.
- 2. Check Power-On Reset on U701, Pin 9 (see Figure 2). If not present, check regulator U705, Pin 2 and transistor Q704.

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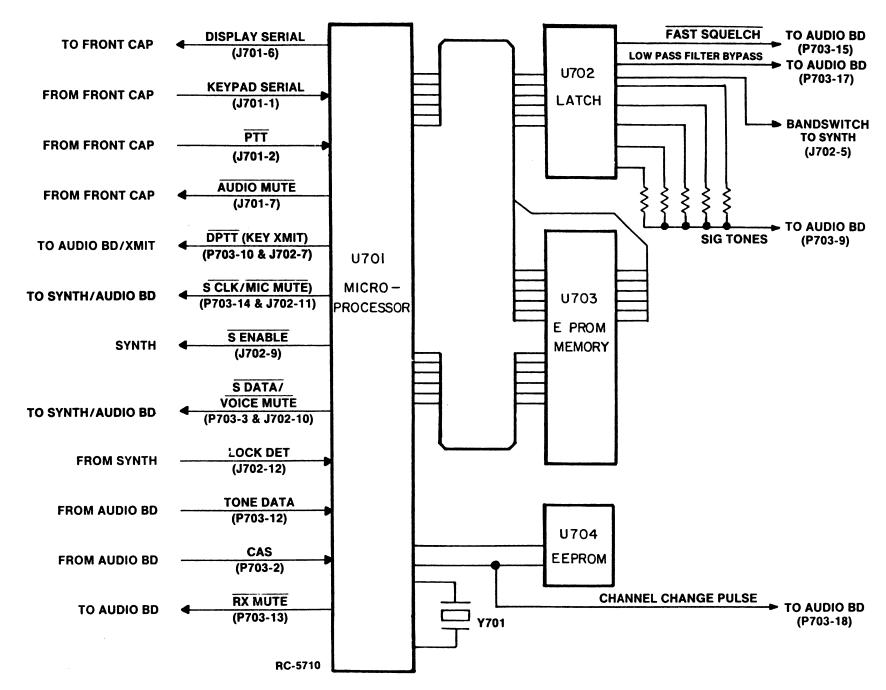


FIGURE 1 - BLOCK DIAGRAM

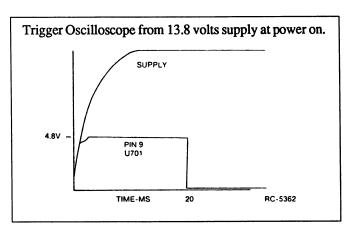


FIGURE 2 - RESET WAVEFORM

3. Check for oscillator activity by examining the ALE clock on U701, Pin 30 (see Figure 3). If not present, examine the system clock on U701, Pin 18 (5 volts pp at 11.059 MHz). The presence of the system clock, but no ALE may indicate a bad U701. If the system clock is not present, suspect Y701 and related components.

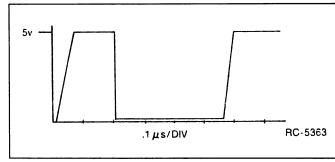


FIGURE 3 - ALE CLOCK

4. All output lines from the microprocessor are pulled high to +5 volts through 50K ohm resistors inside the microprocessor. If a line is high, you may ground that pin and monitor the results. How ever, if a line is low, the line may not be forced to +5 volts.

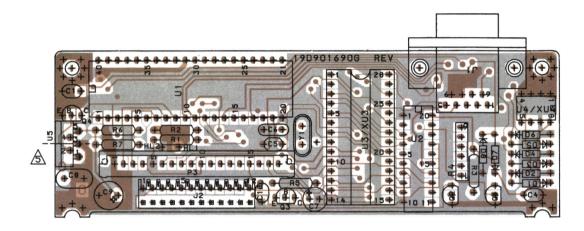


GE Mobile Communications

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LBI-31923 **OUTLINE DIAGRAM**

TOP VIEW



(19D901690, Sh. 2, Rev. 1) (19A705378, Sh. 1, Rev. 0) (19A705378, Sh. 2, Rev. 0)

5. US SHALL NOT OVERHANG EDGE OF PWB.
6. P3 SHALL BE FLUSH TO PWB WITHIN 0.25. 8. REFERENCE DESIGNATIONS SHOWN ARE
ABBREVIATED; FOR COMPLETE DESIGNATION
ADD 700 TO NO. SHOWN. ETC J1-J701.

9. THE FOLLOWING ITEMS ARE ELECTROSTATIC SENSITIVE DEVICES
REQUIRING SPECIAL CARE PER 19A701294; U1,U2, U3 AND U4.

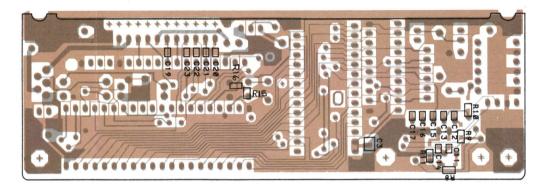
10.THE MAX. HEIGHT ABOVE THE PWB OF ALL PARTS IN THE AI GROUP
(ITEM 9) MUST BE MAINTAINED WHEN THOSE PARTS ARE NOT AI'D.

THE (+) LEAD OF C7 IS THE LONGEST OF THE TWO.

12.PIN 1 OF R4 IDENTIFIED BY DOT, COLOR STRIPE, VENDOR'S
LOGO OR NOTCH.

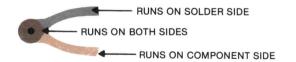
LOGO OR NOTCH.

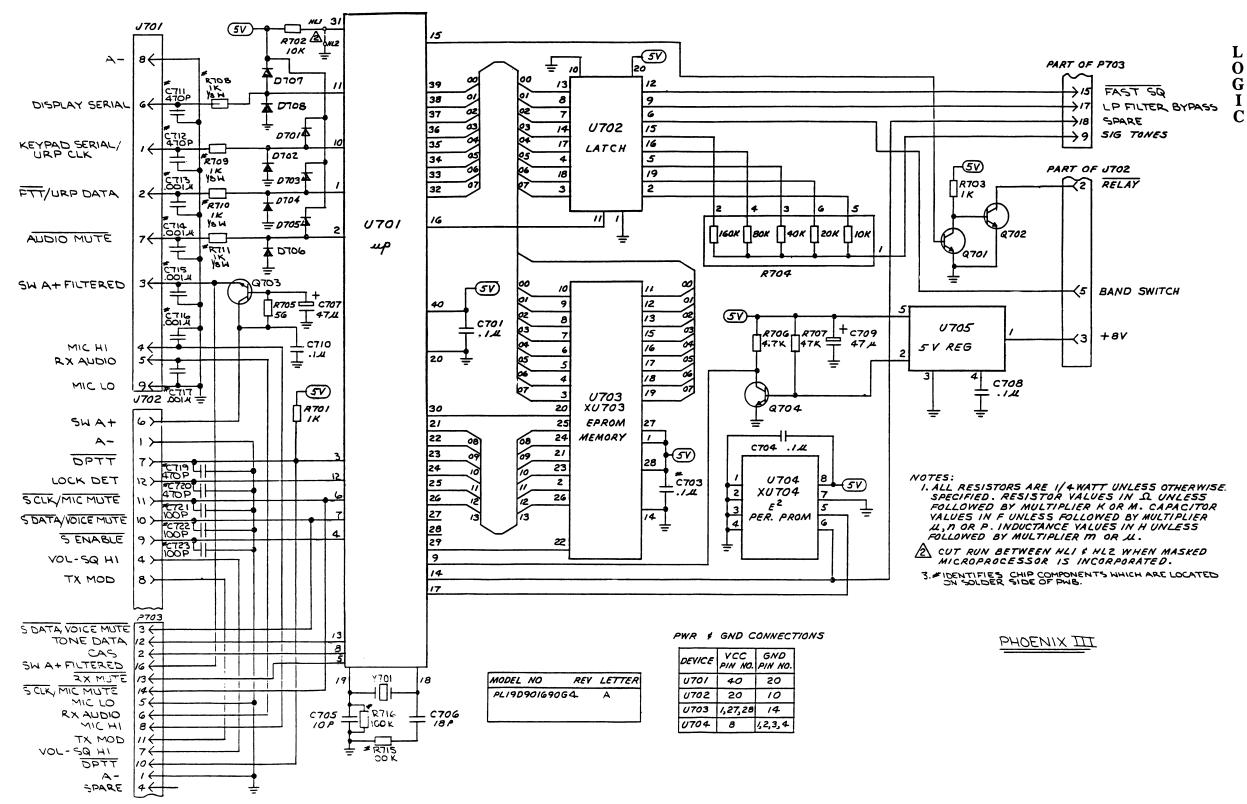
BOTTOM VIEW



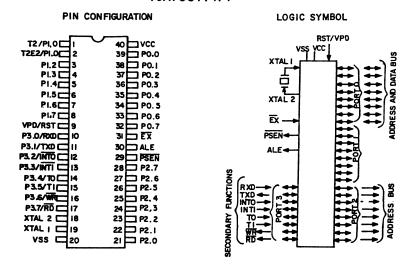
VIEW FROM BACK OF BOARD

(19D901690, Sh. 2, Rev. 1) (19A705378, Sh. 3, Rev. 0) (19A705378, Sh. 4, Rev. 0)

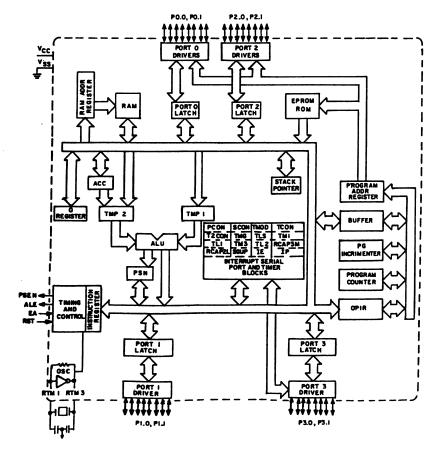




HMOS 8-BIT MICROPROCESSOR (U701) 19A703714P1

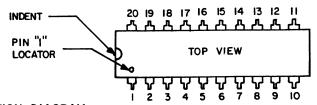


FUNCTION DIAGRAM

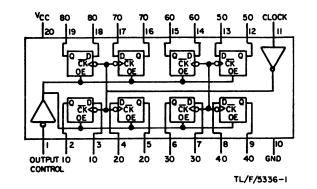


OCTAL 3- STATE D FLIP FLOP (U702) 19A704380PI2 (74HC374)

PIN CONFIGURATION



FUNCTION DIAGRAM



TRUTH TABLE

OUTPUT	CLOCK	DATA	OUTPUT
- L	†	ΗL	HL
L H	L X	X X	Q _o Z

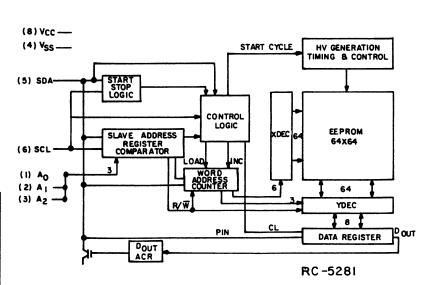
- H = HIGH LEVEL, L=LOW LEVEL X = DON'T CARE
- T = TRANSITION FROM LOW-TO-HIGH
- Z = HIGH IMPEDANCE STATE
- Q₀=THE LEVEL OF THE OUTPUT BEFORE STEADY STATE INPUT CONDITIONS WERE ESTABLISHED.

DIGITAL 512X8 EEPROM (U704) 19A704724PI

PIN CONFIGURATION

I AO TO VSS 2 AND 3 A AND A ADDRESS INPUTS 4 VSS 5 SDA SERIAL DATA 12C 6 SCL SERIAL CLOCK BUS 7 TEST INPUT TO VSS 8 VCC

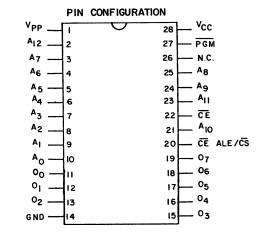
FUNCTION DIAGRAM



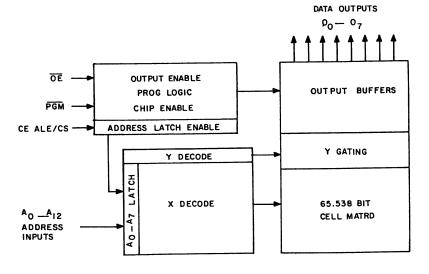
O G I C

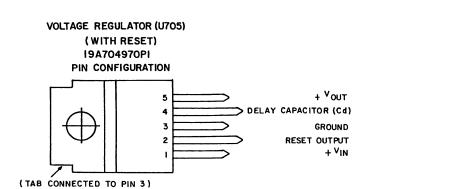
EPROM (U703)

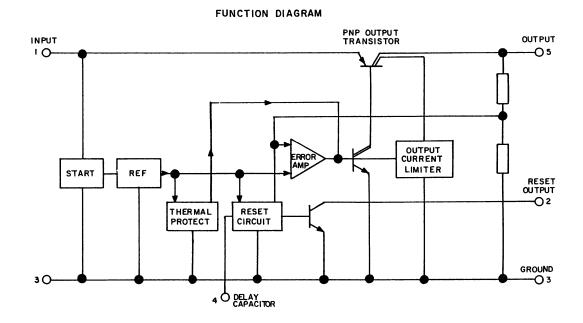
SEE PART LIST



FUNCTION DIAGRAM







RC-5286

LBI-31923 PARTS LIST

PARTS LIST

MVS LOGIC BOARD 19D901690G4 ISSUE 3

C701 19 C703 19 C704 19 C705 19 C706 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 19 C711 19 C712 C713 15	GE PART NO. .9A700121P106 .9A702052P26 .9A700121P106 .9A700235P13 .9A700235P16 .9A704879P2 P644ACP410K .9A701534P9	DESCRIPTION DESCRIPTION	U702 U704 U705 XU703 XU704	19A704380P12 19A704724P1 19A704970P1 19A700156P3 19A700156P15	Digital: sim to: 74HC374. Digital: EE PROM; sim to XICOR X2404P. Voltage Regulator, 5 volts; sim to: SGS L3
C701 19 C703 19 C704 19 C705 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 19 C711 19 C712 C713 15	.9A700121P106 .9A702052P26 .9A700121P106 .9A700235P13 .9A700235P16 .9A704879P2 r644ACP410K .9A701534P9	Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 0.1 uF + or -10%, 50 VDCW. Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 10 pF + or -5%, 50 VDCW. Ceramic: 18 pF + or -5%, 50 VDCW.	U705 XU703 XU704	19A704970P1 19A700156P3	Voltage Regulator, 5 volts; sim to: SGS L3 SOCKETS Integrated circuit: 28 contacts; sim to AM 640362P3. Integrated circuit: 8 positions; sim to Bu
C701 19 C703 19 C704 19 C705 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 19 C711 19 C712 C713 15	.9A700121P106 .9A702052P26 .9A700121P106 .9A700235P13 .9A700235P16 .9A704879P2 r644ACP410K .9A701534P9	Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 0.1 uF + or -10%, 50 VDCW. Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 10 pF + or -5%, 50 VDCW. Ceramic: 18 pF + or -5%, 50 VDCW.	XU703 XU704	19A700156P3	Integrated circuit: 28 contacts; sim to AM 640362P3. Integrated circuit: 8 positions; sim to Bu
C703 19 C704 19 C705 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 19 C711 and c712 C713 15	.9A702052P26 .9A700121P106 .9A700235P13 .9A700235P16 .9A704879P2 r644ACP410K .9A701534P9	Ceramic: 0.1 uP + or -20%, 50 VDCW. Ceramic: 0.1 uP + or - 10%, 50 VDCW. Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 10 pP + or -5%, 50 VDCW. Ceramic: 18 pF + or -5%, 50 VDCW.	XU704	1	Integrated circuit: 28 contacts; sim to AM 640362P3. Integrated circuit: 8 positions; sim to Bu
C703 19 C704 19 C705 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 and and c712 C713 19	.9A702052P26 .9A700121P106 .9A700235P13 .9A700235P16 .9A704879P2 r644ACP410K .9A701534P9	Ceramic: 0.1 uP + or -20%, 50 VDCW. Ceramic: 0.1 uP + or - 10%, 50 VDCW. Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 10 pP + or -5%, 50 VDCW. Ceramic: 18 pF + or -5%, 50 VDCW.		19A700156P15	Integrated circuit: 8 positions; sim to Bu
C703 19 C704 19 C705 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 and and c712 C713 19	.9A702052P26 .9A700121P106 .9A700235P13 .9A700235P16 .9A704879P2 r644ACP410K .9A701534P9	Ceramic: 0.1 uF + or - 10%, 50 VDCW. Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 10 pF + or -5%, 50 VDCW. Ceramic: 18 pF + or -5%, 50 VDCW.		198700130113	DILB 8P-108.
C704 19 C705 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 and ard c712 C713 15	.9A700121P106 .9A700235P13 .9A700235P16 .9A704879P2 P644ACP410K	Ceramic: 0.1 uF + or -20%, 50 VDCW. Ceramic: 10 pF + or -5%, 50 VDCW. Ceramic: 18 pF + or -5%, 50 VDCW.	¥701		
C705 19 C706 19 C707 19 C708 76 C709 19 C710 19 C711 19 and C712 C713 19	.9A700235P13 .9A700235P16 .9A704879P2 .9A704870F0 .9A701534P9	Ceramic: 10 pF + or -5%, 50 VDCW. Ceramic: 18 pF + or -5%, 50 VDCW.	¥701		
C706 19 C707 19 C708 T6 C709 19 C710 19 C711 19 and C712 C713 19	19A700235P16 19A704879P2 1644ACP410K 19A701534P9	Ceramic: 18 pF + or -5%, 50 VDCW.	¥701	l .	
C707 19 C708 T6 C709 19 C710 19 C711 19 and c712 C713 19	19A704879P2 F644ACP410K 19A701534P9	1		19A702511G15	Quartz: 11.059200 MHz.
C708 T6 C709 19 C710 19 C711 19 and C712 C713 19	F644ACP410K L9A701534P9				
C709 19 C710 19 C711 19 and C712 C713 19	19A701534P9	Electrolytic: 47 uF + or -20%, 16 VDCW.			
C710 19 C711 19 and C712 C713 19		Polyester: 0.1 uF + or -10%, 50 VDCW.			· · · · · · · · · · · · · · · · · · ·
C711 19 and C712 C713 19	19A700121P106	Tantalum: 47 uF + or -20%, 6.3 VDCW.	ı		
and C712 C713		Ceramic: 0.1 uF + or -20%, 50 VDCW.			
	L9A702052P3	Ceramic: 470 pF + or - 10%, 50 VDCW.			
thru C717	19A702052P5	Ceramic: 1000 pF + or -10%, 50 VDCW.			
C719 19 and C720	19A702052P3	Ceramic: 470 pF + or - 10%, 50 VDCW.			
	19A702061P61	Ceramic: 100 pP + or - 5%, 50 VDCW, temp coef 0 + or - 30 PPM.			
1		DIODES			
D701 19 thru D708	19A700028P1	Silicon, fast recovery: fwd current 75 mA, 75 PIV; sim to Type lN4148.		1	
J701 19	19B209727P29	Connector.			
J702 19	19A704779P11	Connector; sim to Molex 22-17-2122.			
P703 19	19A704874P1	Connector: sim to: Elco 00-9021-18-12-00-339.			
				1	
Q701 19	19A700023P2	Silicon, NPN: sim to 2N3904.	1		İ
Q702 19 and Q703	19A702503P2	Silicon, NPN.	İ		
Q704 1	19A700023P2	Silicon, NPN: sim to 2N3904.			
İ		RESISTORS			
R701 H:	H212CRP210C	Deposited carbon: 1K ohms + or -5%, 1/4 w.			
R702 H	H212CRP310C	Deposited carbon: 10K ohms + or - 5%, 1/4 w.		1	
R703 H	H212CRP210C	Deposited carbon: 1K ohms + or -5%, 1/4 w.			
R704 1	19A704885P5	Resistive Network: + or -2%, 1/8 w.		1	
R705 H	H212CRP056C	Deposited carbon: 56 ohms + or -5%, 1/4 w.		1	
R706 H	H212CRP247C	Deposited carbon: 4.7K ohms + or -5%, 1/4 w.			1
R707 H	H212CRP347C	Deposited carbon: 47K ohms + or -5%, 1/4 w.	1		
R708 1 thru R711	19B800607P102	Metal film: 1K ohms + or - 5%, 200 VDCW, 1/8 w.			
R715 1 and R716	19B800607P104	Metal film: 100K ohms + or - 5%, 200 VDCW, 1/8 W.			

DESCRIPTION

- - - - - - - INTEGRATED CIRCUITS - - - -

Microcomputer: HMOS, 8-BIT.

GE PART NO.

19A703714P1

SYMBOL

U701

^{*}COMPONENTS ADDED, DELETED OR CHANGED BY PRODUCTION CHANGES